

Features

Type

MPBW30N65E

- Easy parallel switching capability due to positive temperature coefficient in V_{CEsat}
- Low V_{CEsat}, fast switching
- High ruggedness, good thermal stability

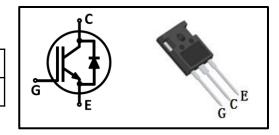
Marking

MP30N65E

Very tight parameter distribution

Applications

- ∎ UPS
- PFC
- PTC Heater
- Climate Compressor



Maximum Rated Values¹

Parameter	Symbol	Value	Unit		
Collector-emitter voltage	V _{CE}	650	V		
DC collector current ²					
T _C =25°C		60			
T _c =100°C		30]		
Pulsed collector current ³	I _{Cpuls}	90			
Diode forward current ²	•	·	- A		
T _C =25°C		40]		
T _C =100°C		20			
Diode pulsed current ³	I _{Fpuls}	90			
Gate-emitter voltage	N	±20	v		
Transient Gate-emitter voltage (t _p ≤10us)	- V _{GE}	±30			
Power dissipation					
T _C =25°C		238	W		
T _c =100°C	- P _{tot}	119			
Operating junction temperature	T _j -55~175		- °C		
Storage temperature	T _{stg}	-55~150			

Package Code

TO-247-3

1:Reference standard: JESD-022 2: limited by Tjmax 3: Tp limited by Tjmax ;



Thermal Characteristics

Parameter	Symbol	Min	Тур	Max	Unit
IGBT thermal resistance, junction-case	R _{thJC}	-	-	0.63	
Diode thermal resistance, junction-case	R _{thJCD}	-	-	1.71	K/W
Thermal Resistance, junction-ambient	R _{thJA}	-	-	40	

Electrical Characteristics (at Tj=25°C, unless otherwise specified) Static Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter breakdown voltage	V _{(BR)CES}	V _{GE} =0V, I _C =1.0mA	650	-	-	
Collector-emitter		V _{GE} =15V, I _C =30A T _j =25°C	-	1.36	1.90	
saturation voltage	V _{CE(sat)}	V _{GE} =15V, I _C =30A T _j =175℃	-	1.62	-	V
Diode forward voltage		V _{GE} =0V,I _F =20A T _j =25°C	-	1.57	1.95	
	V _F	V _{GE} =0V, I _F =20A T _j =175℃	-	1.42	-	
G-E threshold voltage	V _{GE(th)}	I_{C} =1.2mA, V_{CE} = V_{GE}	4.5	5.5	6.5	
C-E leakage current	1	V _{CE} =650V, V _{GE} =0V T _j =25°C	-	-	0.01	mA
	I _{CES}	V _{CE} =650V, V _{GE} =0V T _j =175℃	-	-	1.0	
G-E leakage current	I _{GES}	V _{CE} =0V, V _{GE} =20V	-	-	250	nA

Dynamic Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input capacitance	C _{iss}	1/ 201/	-	2173	-	
Output capacitance	C _{oss}	V _{CE} =30V, V _{GE} =0V,	-	109	-	рF
Reverse transfer capacitance	C _{rss}	f=1MHz	-	24	-	
Gate charge	Q _G	V _{CC} =400V, I _C =30A, V _{GE} =15V	-	96	-	nC



IGBT Switching Characteristics

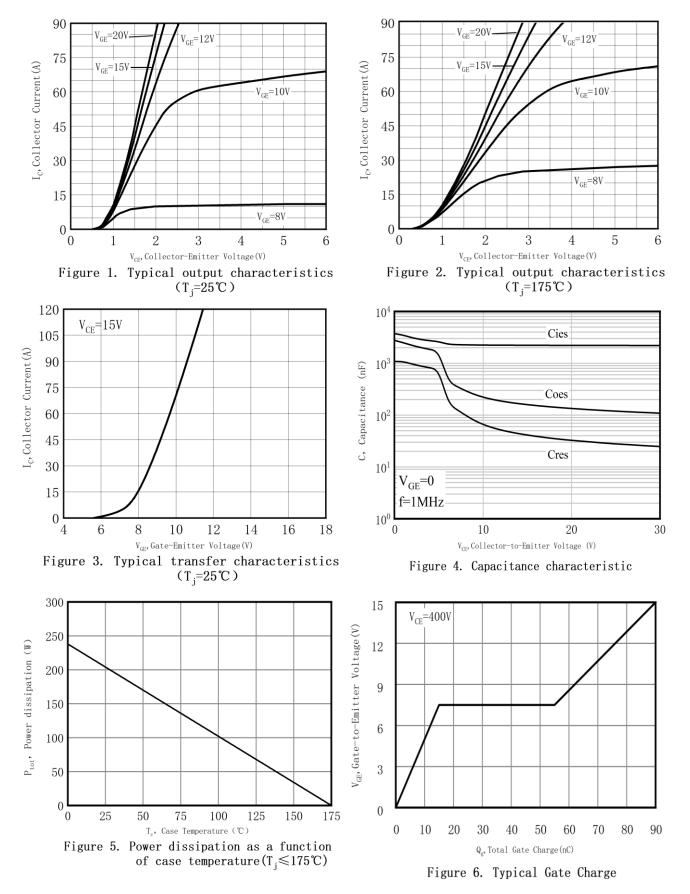
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Turn-on delay time	t _{d(on)}		-	78	-	
Rise time	t _r] T _i =25°C,	-	47	-	
Turn-off delay time	t _{d(off)}	V _{CC} =400V,	-	176	-	ns
Fall time	t _f	│ I _C =30A, │ V _{GE} =0/15V,	-	43	-	
Turn-on energy	E _{on}	$R_{g}=10\Omega$,	-	0.56	-	
Turn-off energy	E _{off}	Inductive load	-	0.65	-	mJ
Total switching energy	E _{ts}	1	-	1.21	-	
Turn-on delay time	t _{d(on)}		-	74	-	
Rise time	t _r	T;=175℃,	-	47	-	
Turn-off delay time	t _{d(off)}	T _j =175℃, V _{CC} =400V,	-	211	-	ns
Fall time	t _f	I _C =30A, V _{GE} =0/15V,	-	76	-	
Turn-on energy	Eon	$R_{g}=10\Omega$,	-	1.0	-	
Turn-off energy	E _{off}	Inductive load	-	0.89	-	mJ
Total switching energy	E _{ts}		-	1.89	-	

Diode Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Diode reverse recovery time	t _{rr}	T _j =25°C, V _R =400V,	-	85.2	-	ns
Diode reverse recovery charge	Q _{rr}	V _R =400V, I _F =30A,	-	0.62	-	μC
Diode peak reverse recovery current	I _{rrm}	di _F /dt=600A/µs	-	13.0	-	А
Diode reverse recovery time	t _{rr}	T _i =175℃,	-	170	-	ns
Diode reverse recovery charge	Q _{rr}	V _R =400V, I _F =30A,	-	2.34	-	uC
Diode peak reverse recovery current	l _{rrm}	di _F /dt=600A/µs	-	27.2	-	А

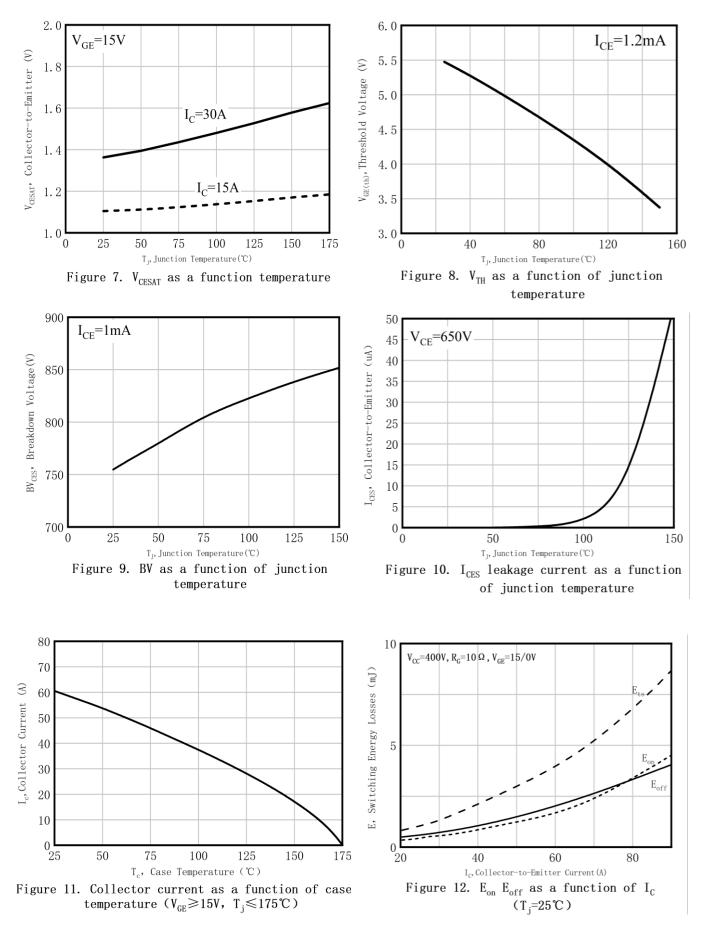


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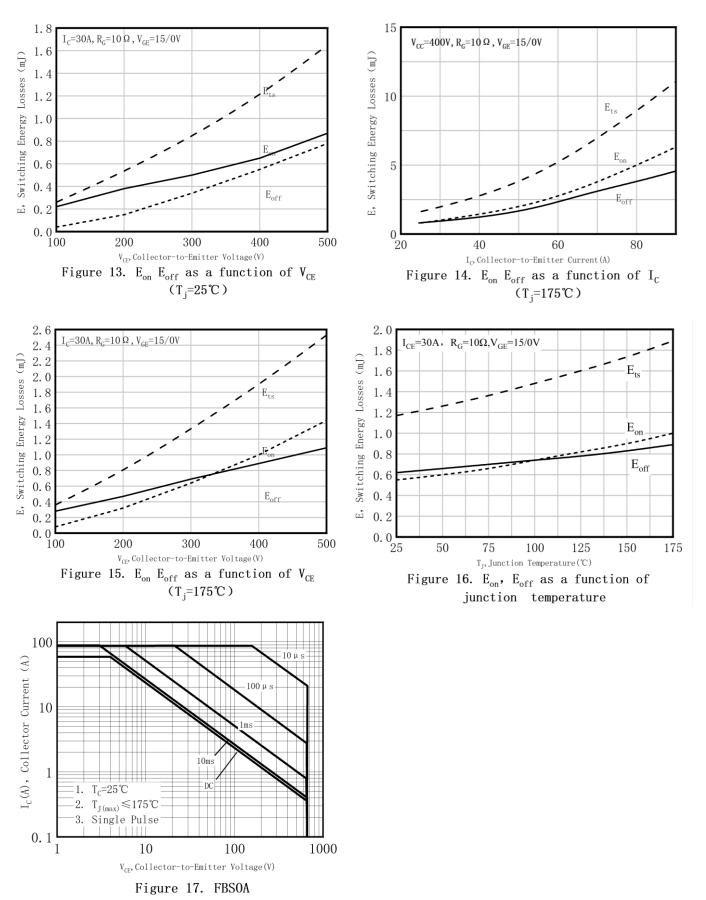


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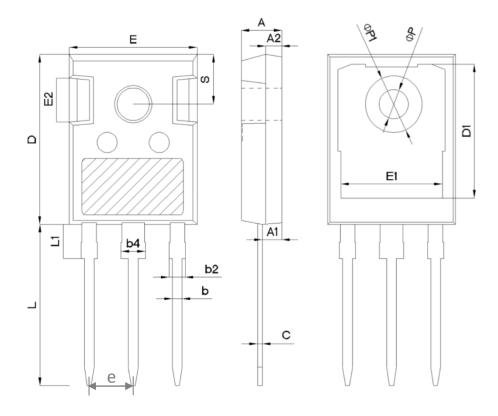


MPBW30N65E





TO-247



		mm	
SYMBOL	MIN	NOM	MAX
А	4.80	5.00	5.20
A1	2.21	2.41	2.61
A2	1.85	2.00	2.15
b	1.11	1.21	1.36
b2	1.91	2.01	2.21
b4	2.91	3.01	3.21
С	0.51	0.61	0.75
D	20.70	21.00	21.30
D1	16.25	16.55	16.85
Е	15.50	15.80	16.10
E1	13.00	13.30	13.60
E2	4.80	5.00	5.20
E3	2.30	2.50	2.70
е		5.44BSC	•
L	19.62	19.92	20.22
L1	-	-	4.30
ФР	3.40	3.60	3.80
ΦΡ1	-	-	7.30
S		6.15BSC	



Revision History:

Revision	Date	Subjects (major changes since last revision)
1.0	2023-2-22	Initial Version



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